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| Application Number     | 10/849,345             |
| Filing Date            | May 19, 2004           |
| First Named Inventor   | Robert H. Burgener, II |
| Group Art Unit         | 3811                   |
| Examiner Name          | TRAN                   |
| Attorney Docket Number | 3398.2.9               |

|                        |          |   | U.S. PATENT                    | DOCUMENTS  |  |  |
|------------------------|----------|---|--------------------------------|--|--|--|
| Examiner<br>Initials * | Cite No. | Document Number                           | Publication Date<br>MM-DD-YYYY | Name of Patentee or Applicant of<br>Cited Document | Pages, Columns, Lines, Where Relevant<br>Passages or Relevant?<br>Figures Appear |  |
|                        |          | Number - Kind Code <sup>2 (Finzent)</sup> |                                |  |  |  |
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| 77                     | U2       | US-6,589,362-B2                           | 07/08/2003                     | Haga   | 7  |  |
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Examiner Signature Date Considered 12-20-2004

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| NON PATENT LITERATURE DOCUMENTS |           |   |     |
|---------------------------------|-----------|---|-----|
| Examiner Initials *             | Cite No.1 | Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published. | T 2 |
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|   |                       |      |        |                    |    |       | _ |
|---|-----------------------|------|--------|--------------------|----|-------|---|
| - | Examiner<br>Signature | · In | ilm mu | Date<br>Considered | 12 | 21/04 | 1 |

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